COM'L: H-7/10/15/25, Q-15/25 MIL: H-10/15/20/25

T-46-19-07

PALCE16V8 Family

EE CMOS 20-Pin Universal Programmable Array Logic

Advanced Micro Devices

DISTINCTIVE CHARACTERISTICS

- **Pin, function and fuse-map compatible with all 20-pin GAL® devices**
- **Electrically erasable CMOS technology provides reconfigurable logic and full testability**
- **High-speed CMOS technology**
  - 7.5 ns propagation delay for "-7" version
  - 10 ns propagation delay for "-10" version
  - 15 ns propagation delay for "-15" version
- **Direct plug-in replacement for the PAL16R8 series and most of the PAL10H8 series**
- **Outputs programmable as registered or combinatorial in any combination**
- **Programmable output polarity**
- **Programmable enable/disable control**
- **Preloadable output registers for testability**
- **Automatic register reset on power up**
- **Cost-effective 20-pin plastic DIP, PLCC, and SOIC packages**
- **Extensive third-party software and programmer support through FusionPLD partners**
- **Fully tested for 100% programming and functional yields and high reliability**

GENERAL DESCRIPTION

The PALCE16V8 is an advanced PAL device built with low-power, high-speed, electrically-erasable CMOS technology. It is functionally compatible with all 20-pin GAL devices. The macrocells provide a universal device architecture. The PALCE16V8 will directly replace the PAL16R8 and PAL10H8 series devices, with the exception of the PAL16C1.

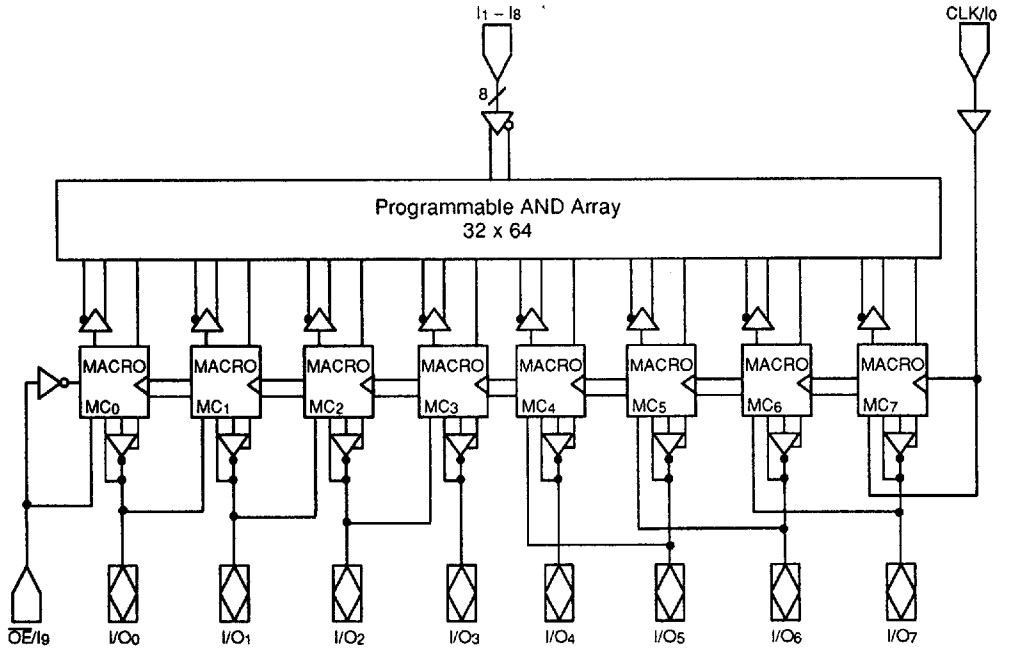
The PALCE16V8 utilizes the familiar sum-of-products (AND/OR) architecture that allows users to implement complex logic functions easily and efficiently. Multiple levels of combinatorial logic can always be reduced to sum-of-products form, taking advantage of the very wide input gates available in PAL devices. The equations are programmed into the device through floating-gate cells in the AND logic array that can be erased electrically.

The fixed OR array allows up to eight data product terms per output for logic functions. The sum of these products feeds the output macrocell. Each macrocell can be programmed as registered or combinatorial with an active-high or active-low output. The output configuration is determined by two global bits and one local bit controlling four multiplexers in each macrocell.

AMD's FusionPLD program allows PALCE16V8 designs to be implemented using a wide variety of popular industry-standard design tools. By working closely with the FusionPLD partners, AMD certifies that the tools provide accurate, quality support. By ensuring that third-party tools are available, costs are lowered because a designer does not have to buy a complete set of new tools for each device. The FusionPLD program also greatly reduces design time since a designer can use a tool that is already installed and familiar. Please refer to the PLD Software Reference Guide for certified development systems and the Programmer Reference Guide for approved programmers.

Publication# 16493 Rev. A Amendment/0
Issue Date: January 1992

BLOCK DIAGRAM



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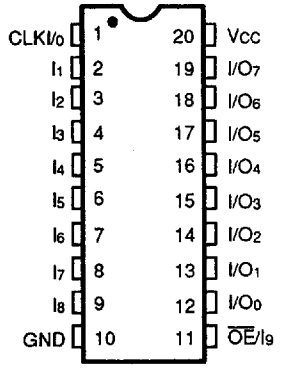
CONNECTION DIAGRAMS
Top View

DIP/SOIC



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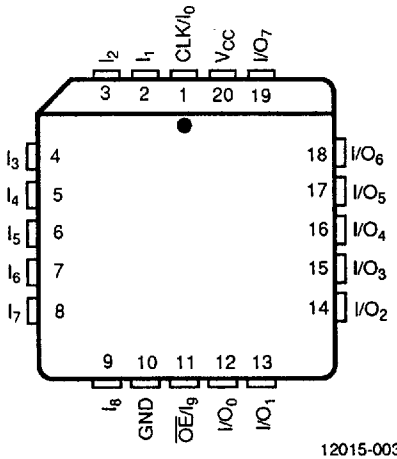
Note: Pin 1 is marked for orientation

PLCC/LCC



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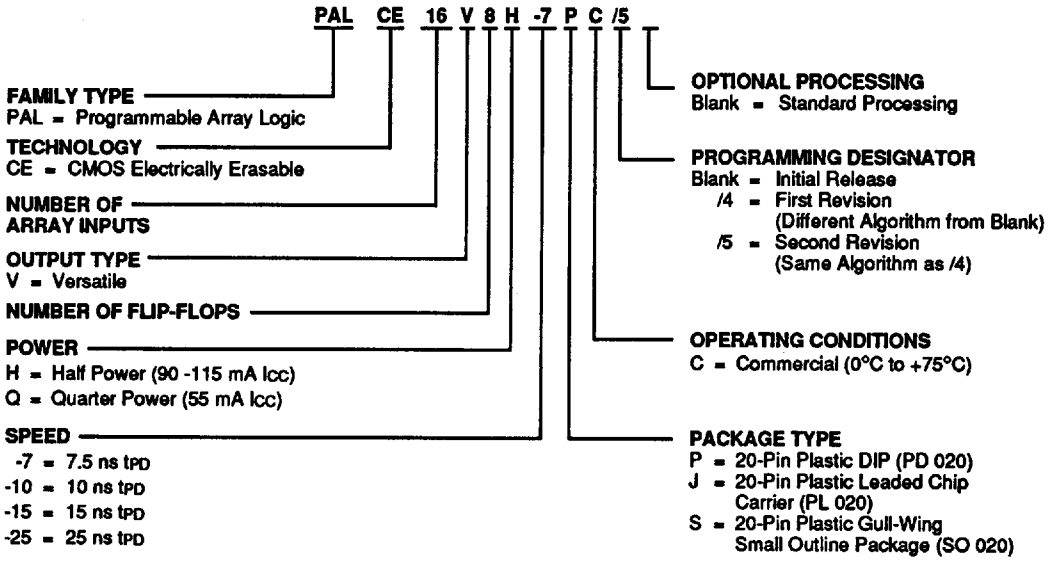
PIN DESIGNATIONS

CLK = Clock
GND = Ground
I = Input
I/O = Input/Output
$\overline{OE}$ = Output Enable
Vcc = Supply Voltage

ORDERING INFORMATION

Commercial Products

AMD programmable logic products for commercial applications are available with several ordering options. The order number (Valid Combination) is formed by a combination of:



Valid Combinations		
PALCE16V8H-7	PC, JC	/5
PALCE16V8H-10	PC, JC, SC	/4, /5
PALCE16V8H-15	PC, JC, SC	Blank, /4
PALCE16V8H-25		
PALCE16V8Q-15	PC, JC	
PALCE16V8Q-25		

Valid Combinations

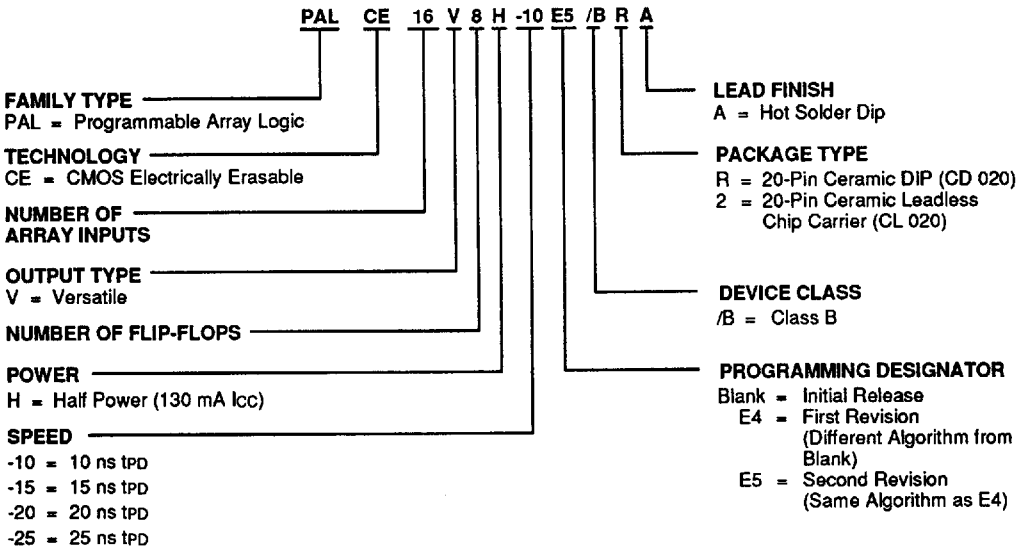
The Valid Combinations table lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations and to check on newly released combinations.

Note: Marked with AMD logo.

ORDERING INFORMATION

APL Products (Military)

AMD programmable logic products for Aerospace and Defense applications are available with several ordering options. APL (Approved Products List) products are fully compliant with MIL-STD-883 requirements. The order number (Valid Combination) is formed by a combination of:



Valid Combinations		
PALCE16V8H-10	E5	/BRA /B2A
PALCE16V8H-15	E4, E5	
PALCE16V8H-20	Blank, E4	
PALCE16V8H-25		

Valid Combinations

The Valid Combinations table lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations and to obtain additional data on AMD's standard military grade products.

Note: Marked with AMD logo.

Group A Tests

Group A tests consist of Subgroups 1, 2, 3, 7, 8, 9, 10, 11.

Military Burn-In

Military burn-in is in accordance with the current revision of MIL-STD-883, Test Method 1015, Conditions A through E. Test conditions are selected at AMD's option.

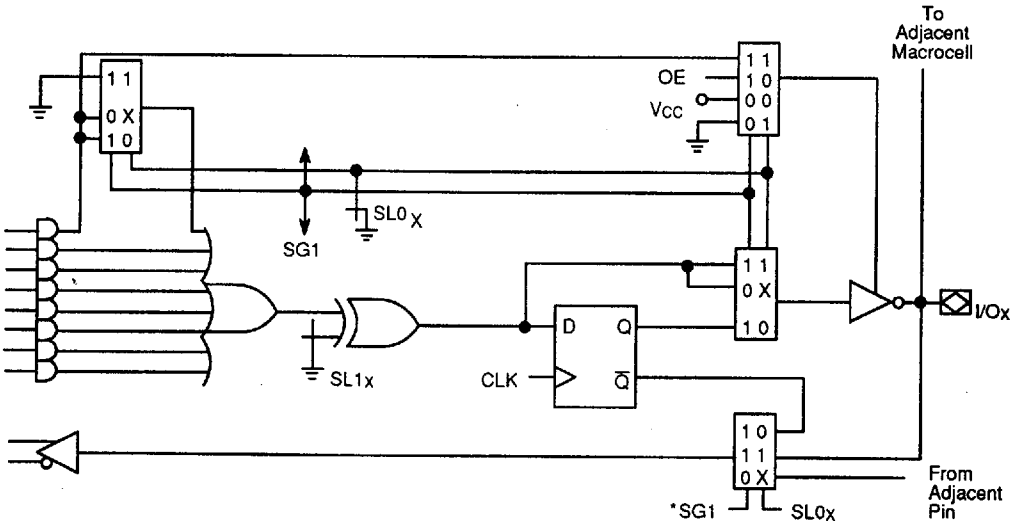
FUNCTIONAL DESCRIPTION

The PALCE16V8 is a universal PAL device. It has eight independently configurable macrocells (MC_0–MC_7). Each macrocell can be configured as registered output, combinatorial output, combinatorial I/O or dedicated input. The programming matrix implements a programmable AND logic array, which drives a fixed OR logic array. Buffers for device inputs have complementary outputs to provide user-programmable input signal polarity. Pins 1 and 11 serve either as array inputs or as clock (CLK) and output enable ($\overline{OE}$), respectively, for all flip-flops.

Unused input pins should be tied directly to V_{CC} or GND. Product terms with all bits unprogrammed (disconnected) assume the logical HIGH state and product terms with both true and complement of any input signal connected assume a logical LOW state.

The programmable functions on the PALCE16V8 are automatically configured from the user's design specification, which can be in a number of formats. The design specification is processed by development software to verify the design and create a programming file. This file, once downloaded to a programmer, configures the device according to the user's desired function.

The user is given two design options with the PALCE16V8. First, it can be programmed as a standard PAL device from the PAL16R8 and PAL10H8 series. The PAL programmer manufacturer will supply device codes for the standard PAL device architectures to be used with the PALCE16V8. The programmer will program the PALCE16V8 in the corresponding architecture. This allows the user to use existing standard PAL device JEDEC files without making any changes to them. Alternatively, the device can be programmed as a PALCE16V8. Here the user must use the PALCE16V8 device code. This option allows full utilization of the macrocell.



*In macrocells MC_0 and MC_7, SG1 is replaced by $\overline{SG0}$ on the feedback multiplexer.

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PALCE16V8 Macrocell

Configuration Options

Each macrocell can be configured as one of the following: registered output, combinatorial output, combinatorial I/O, or dedicated input. In the registered output configuration, the output buffer is enabled by the $\overline{OE}$ pin. In the combinatorial configuration, the buffer is either controlled by a product term or always enabled. In the dedicated input configuration, it is always disabled. With the exception of MC_0 and MC_7, a macrocell configured as a dedicated input derives the input signal from an adjacent I/O. MC_0 derives its input from pin 11 ($\overline{OE}$) and MC_7 from pin 1 (CLK).

The macrocell configurations are controlled by the configuration control word. It contains 2 global bits (SG0 and SG1) and 16 local bits ($SL0_0$ through $SL0_7$ and $SL1_0$ through $SL1_7$). SG0 determines whether registers will be allowed. SG1 determines whether the PALCE16V8 will emulate a PAL16R8 family or a PAL10H8 family device. Within each macrocell, $SL0_x$, in conjunction with SG1, selects the configuration of the macrocell, and $SL1_x$ sets the output as either active low or active high for the individual macrocell.

The configuration bits work by acting as control inputs for the multiplexers in the macrocell. There are four multiplexers: a product term input, an enable select, an output select, and a feedback select multiplexer. SG1 and $SL0_x$ are the control signals for all four multiplexers. In MC_0 and MC_7, $\overline{SG0}$ replaces SG1 on the feedback multiplexer. This accommodates CLK being the adjacent pin for MC_7 and $\overline{OE}$ the adjacent pin for MC_0.

Registered Output Configuration

The control bit settings are SG0 = 0, SG1 = 1 and $SL0_x$ = 0. There is only one registered configuration. All eight product terms are available as inputs to the OR gate. Data polarity is determined by $SL1_x$. The flip-flop is loaded on the LOW-to-HIGH transition of CLK. The feedback path is from $\overline{Q}$ on the register. The output buffer is enabled by $\overline{OE}$.

Combinatorial Configurations

The PALCE16V8 has three combinatorial output configurations: dedicated output in a non-registered device, I/O in a non-registered device and I/O in a registered device.

Dedicated Output In a Non-Registered Device

The control bit settings are SG0 = 1, SG1 = 0 and $SL0_x$ = 0. All eight product terms are available to the OR gate. Although the macrocell is a dedicated output, the feedback is used, with the exception of pins 15 and 16. Pins 15 and 16 do not use feedback in this mode. Because CLK and $\overline{OE}$ are not used in a non-registered device, pins 1 and 11 are available as input signals. Pin 1 will use the feedback path of MC_7 and pin 11 will use the feedback path of MC_0.

Combinatorial I/O In a Non-Registered Device

The control bit settings are SG0 = 1, SG1 = 1, and $SL0_x$ = 1. Only seven product terms are available to the OR gate. The eighth product term is used to enable the output buffer. The signal at the I/O pin is fed back to the AND array via the feedback multiplexer. This allows the pin to be used as an input.

Because CLK and $\overline{OE}$ are not used in a non-registered device, pins 1 and 11 are available as inputs. Pin 1 will use the feedback path of MC_7 and pin 11 will use the feedback path of MC_0.

Combinatorial I/O in a Registered Device

The control bit settings are SG0 = 0, SG1 = 1 and $SL0_x$ = 1. Only seven product terms are available to the OR gate. The eighth product term is used as the output enable. The feedback signal is the corresponding I/O signal.

Dedicated Input Configuration

The control bit settings are SG0 = 1, SG1 = 0 and $SL0_x$ = 1. The output buffer is disabled. Except for MC_0 and MC_7 the feedback signal is an adjacent I/O. For MC_0 and MC_7 the feedback signals are pins 1 and 11. These configurations are summarized in Table 1 and illustrated in Figure 2.

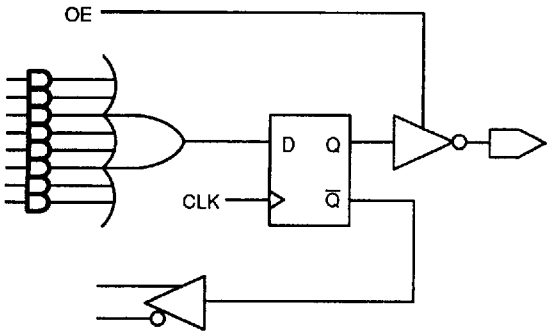
Table 1. Macrocell Configuration

SG0	SG1	$SL0_x$	Cell Configuration	Devices Emulated
Device Uses Registers				
0	1	0	Registered Output	PAL16R8, 16R6, 16R4
0	1	1	Combinatorial I/O	PAL16R6, 16R4
Device Uses No Registers				
1	0	0	Combinatorial Output	PAL10H8, 12H6, 14H4, 16H2, 10L8, 12L6, 14L4, 16L2
1	0	1	Input	PAL12H6, 14H4, 16H2, 12L6, 14L4, 16L2
1	1	1	Combinatorial I/O	PAL16L8

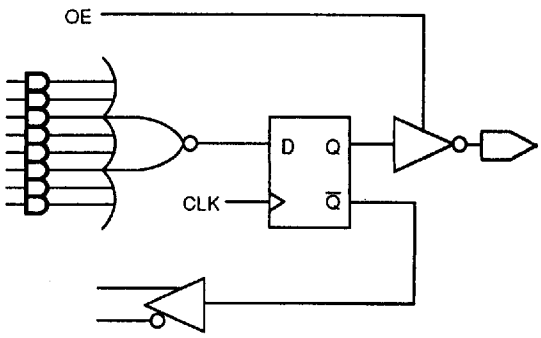
Programmable Output Polarity

The polarity of each macrocell can be active-high or active-low, either to match output signal needs or to reduce product terms. Programmable polarity allows Boolean expressions to be written in their most compact form (true or inverted), and the output can still be of the desired polarity. It can also save "DeMorganizing" efforts.

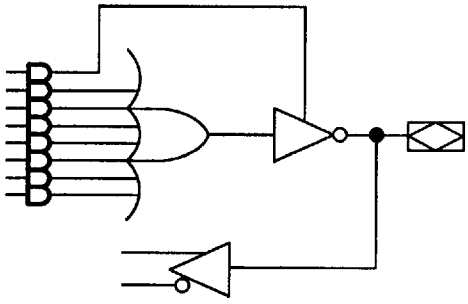
Selection is through a programmable bit $SL1_x$ which controls an exclusive-OR gate at the output of the AND/OR logic. The output is active high if $SL1_x$ is 1 and active low if $SL1_x$ is 0.



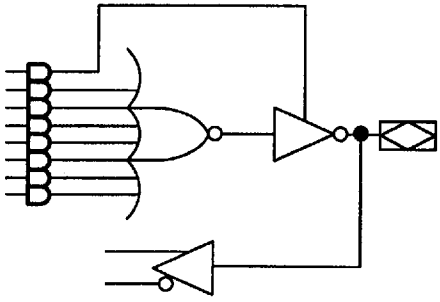
Registered Active Low



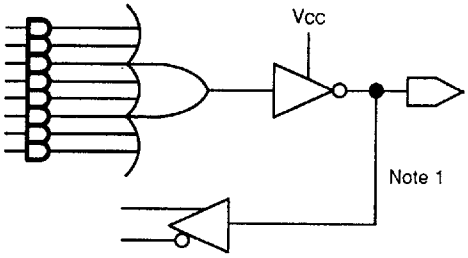
Registered Active High



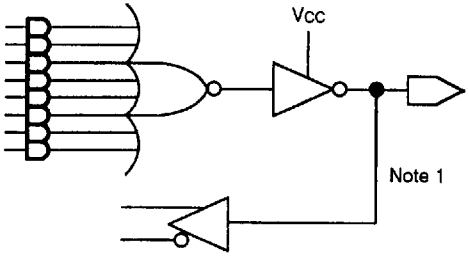
Combinatorial I/O Active Low



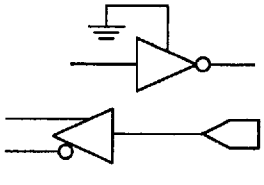
Combinatorial I/O Active High



Combinatorial Output Active Low



Combinatorial Output Active High



Dedicated Input

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Notes:

1. Feedback is not available on pins 15 and 16 in the combinatorial output mode.
2. This configuration is not available on pins 15 and 16.

Figure 2. Macrocell Configurations

Power-Up Reset

All flip-flops power up to a logic LOW for predictable system initialization. Outputs of the PALCE16V8 will depend on whether they are selected as registered or combinatorial. If registered is selected, the output will be HIGH. If combinatorial is selected, the output will be a function of the logic.

Register Preload

The register on the PALCE16V8 can be preloaded from the output pins to facilitate functional testing of complex state machine designs. This feature allows direct loading of arbitrary states, making it unnecessary to cycle through long test vector sequences to reach a desired state. In addition, transitions from illegal states can be verified by loading illegal states and observing proper recovery.

Security Bit

A security bit is provided on the PALCE16V8 as a deterrent to unauthorized copying of the array configuration patterns. Once programmed, this bit defeats readback and verification of the programmed pattern by a device programmer, securing proprietary designs from competitors. The bit can only be erased in conjunction with the array during an erase cycle.

Electronic Signature Word

An electronic signature word is provided in the PALCE16V8 device. It consists of 64 bits of programmable memory that can contain user-defined data. The signature data is always available to the user independent of the security bit.

Programming and Erasing

The PALCE16V8 can be programmed on standard logic programmers. It also may be erased to reset a previously configured device back to its virgin state. Erasure is automatically performed by the programming hardware. No special erase operation is required.

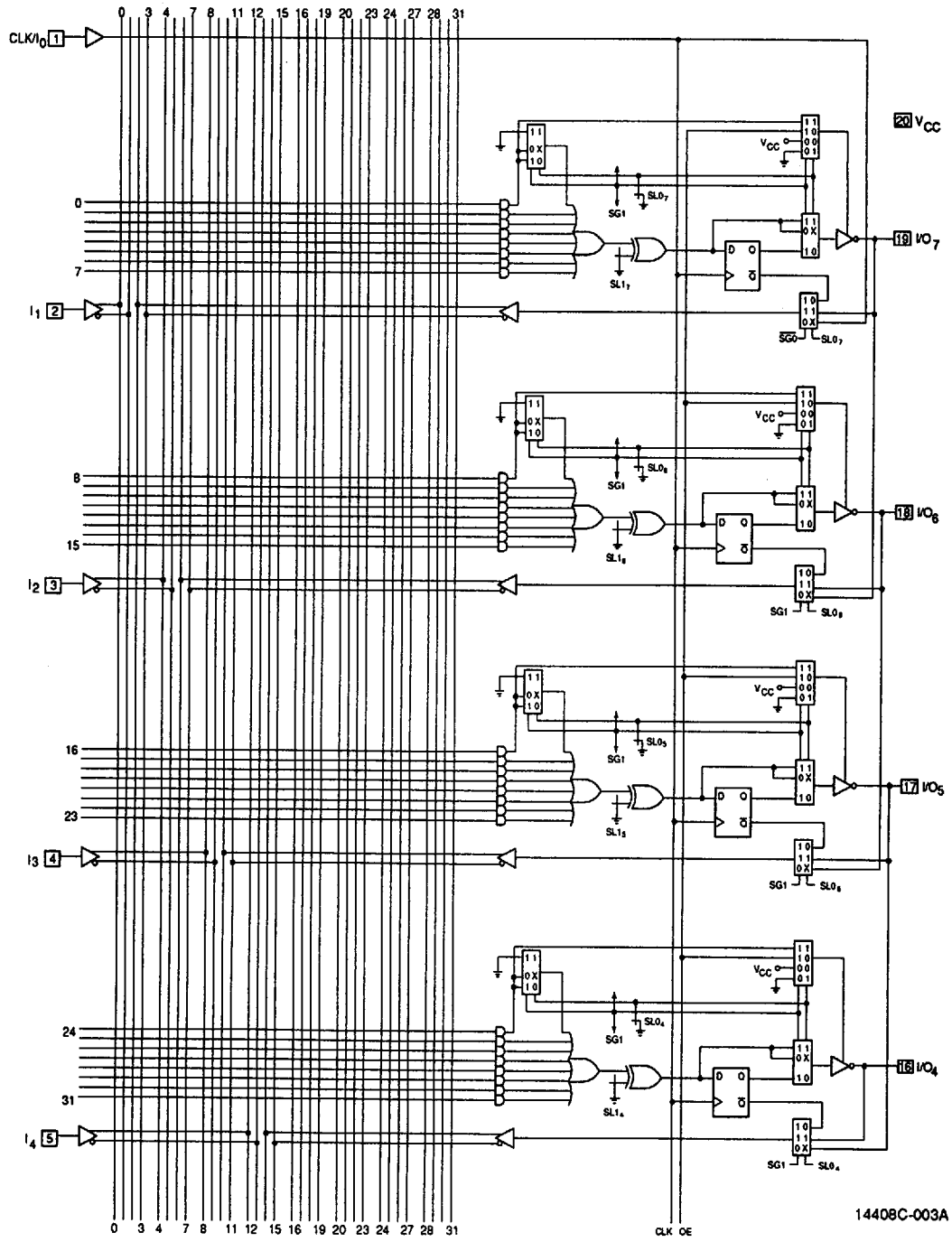
Quality and Testability

The PALCE16V8 offers a very high level of built-in quality. The erasability of the device provides a direct means of verifying performance of all AC and DC parameters. In addition, this verifies complete programmability and functionality of the device to provide the highest programming yields and post-programming functional yields in the industry.

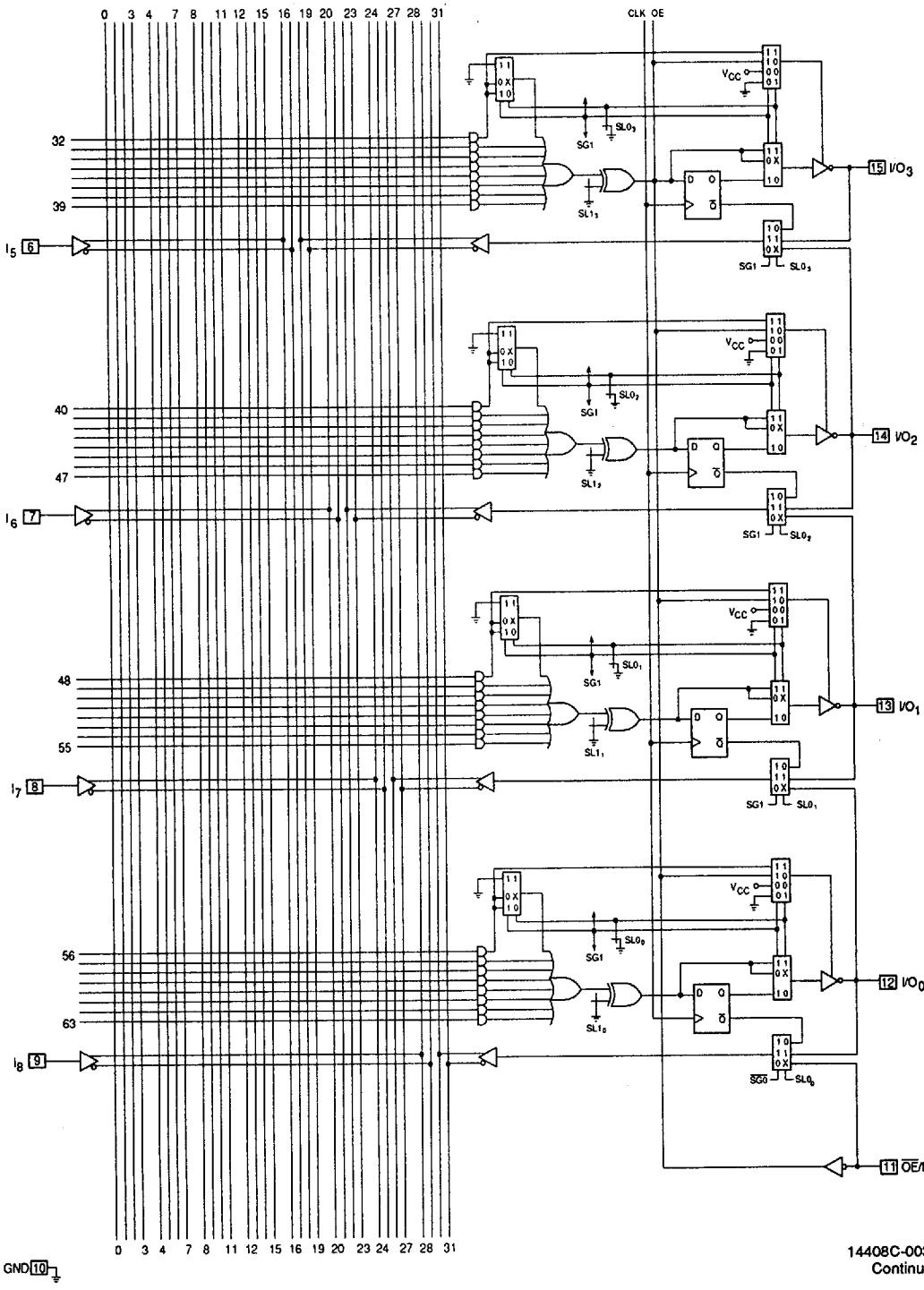
Technology

The high-speed PALCE16V8 is fabricated with AMD's advanced electrically erasable (EE) CMOS process. The array connections are formed with proven EE cells. Inputs and outputs are designed to be compatible with TTL devices. This technology provides strong input clamp diodes, output slew-rate control, and a grounded substrate for clean switching.

LOGIC DIAGRAM



LOGIC DIAGRAM (Continued)



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Continued

ABSOLUTE MAXIMUM RATINGS

Storage Temperature	−65°C to +150°C
Ambient Temperature with Power Applied	−55°C to +125°C
Supply Voltage with Respect to Ground	−0.5 V to +7.0 V
DC Input Voltage	−0.5 V to V_{CC} + 0.5 V
DC Output or I/O Pin Voltage	−0.5 V to V_{CC} + 0.5 V
Static Discharge Voltage	2001 V
Latchup Current (T_A = 0°C to 75°C)	100 mA

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

OPERATING RANGES

Commercial (C) Devices

Temperature (T_A) Operating in Free Air	0°C to +75°C
Supply Voltage (V_{CC}) with Respect to Ground	+4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
V_{OH}	Output HIGH Voltage	I_{OH} = −3.2 mA V_{IN} = V_{IH} or V_{IL} V_{CC} = Min.	2.4		V
V_{OL}	Output LOW Voltage	I_{OL} = 24 mA V_{IN} = V_{IH} or V_{IL} V_{CC} = Min.		0.5	V
V_{IH}	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		V
V_{IL}	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	V
I_{IH}	Input HIGH Leakage Current	V_{IN} = 5.25 V, V_{CC} = Max. (Note 2)		10	µA
I_{IL}	Input LOW Leakage Current	V_{IN} = 0 V, V_{CC} = Max. (Note 2)		−100	µA
I_{OZH}	Off-State Output Leakage Current HIGH	V_{OUT} = 5.25 V, V_{CC} = Max. V_{IN} = V_{IH} or V_{IL} (Note 2)		10	µA
I_{OZL}	Off-State Output Leakage Current LOW	V_{OUT} = 0 V, V_{CC} = Max. V_{IN} = V_{IH} or V_{IL} (Note 2)		−100	µA
I_{SC}	Output Short-Circuit Current	V_{OUT} = 0.5 V V_{CC} = Max. (Note 3)	−30	−150	mA
I_{CC}	Supply Current (Dynamic)	Outputs Open (I_{OUT} = 0 mA) V_{CC} = Max., f = 25 MHz		115	mA

Notes:

1. These are absolute values with respect to device ground and all overshoots due to system or tester noise are included.
2. I/O pin leakage is the worst case of I_{IL} and I_{OZL} (or I_{IH} and I_{OZH}).
3. Not more than one output should be shorted at a time and duration of the short-circuit should not exceed one second. V_{OUT} = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Descriptions	Test Conditions		Typ.	Unit
C_{IN}	Input Capacitance	V_{IN} = 2.0 V	V_{CC} = 5.0 V, T_A = 25°C,	5	pF
C_{OUT}	Output Capacitance	V_{OUT} = 2.0 V	f = 1 MHz	8	pF

Note:

1. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

Parameter Symbol	Parameter Description			Min.	Max.	Unit
t_{PD}	Input or Feedback to Combinatorial Output		8 Outputs Switching		7.5	ns
			1 Output Switching		7	ns
t_S	Setup Time from Input or Feedback to Clock			5		
t_H	Hold Time			0		ns
t_{CO}	Clock to Output				5	ns
t_{WL}	Clock Width	LOW		4		ns
t_{WH}		HIGH		4		ns
f_{MAX}	Maximum Frequency (Note 3)	External Feedback	1/(ts+tco)	100		MHz
		Internal Feedback (f_{CNT})		125		
		No Feedback	1/(t_{WH}+t_{WL})	125		MHz
t_{PZX}	$\overline{OE}$ to Output Enable				6	ns
t_{PXZ}	$\overline{OE}$ to Output Disable				6	ns
t_{EA}	Input to Output Enable Using Product Term Control				9	ns
t_{ER}	Input to Output Disable Using Product Term Control				9	ns

Notes:

2. See Switching Test Circuit for test conditions.
3. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.

ABSOLUTE MAXIMUM RATINGS

Storage Temperature	−65°C to +150°C
Ambient Temperature with Power Applied	−55°C to +125°C
Supply Voltage with Respect to Ground	−0.5 V to +7.0 V
DC Input Voltage	−0.5 V to V_{CC} + 0.5 V
DC Output or I/O Pin Voltage	−0.5 V to V_{CC} + 0.5 V
Static Discharge Voltage	2001 V
Latchup Current (T_A = 0°C to 75°C)	100 mA

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OPERATING RANGES

Commercial (C) Devices

Temperature (T_A) Operating in Free Air	0°C to +75°C
Supply Voltage (V_{CC}) with Respect to Ground	+4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

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V_{IH}	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		V
V_{IL}	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	V
I_{IH}	Input HIGH Leakage Current	V_{IN} = 5.25 V, V_{CC} = Max. (Note 2)		10	µA
I_{IL}	Input LOW Leakage Current	V_{IN} = 0 V, V_{CC} = Max. (Note 2)		−10	µA
I_{OZH}	Off-State Output Leakage Current HIGH	V_{OUT} = 5.25 V, V_{CC} = Max. V_{IN} = V_{IH} or V_{IL} (Note 2)		10	µA
I_{OZL}	Off-State Output Leakage Current LOW	V_{OUT} = 0 V, V_{CC} = Max. V_{IN} = V_{IH} or V_{IL} (Note 2)		−10	µA
I_{SC}	Output Short-Circuit Current	V_{OUT} = 0.5 V V_{CC} = Max. (Note 3)	−30	−150	mA
I_{CC}	Supply Current (Dynamic)	Outputs Open (I_{OUT} = 0 mA) V_{CC} = Max., f = 25 MHz		115	mA

Notes:

1. These are absolute values with respect to device ground and all overshoots due to system or tester noise are included.
2. I/O pin leakage is the worst case of I_{IL} and I_{OZL} (or I_{IH} and I_{OZH}).
3. Not more than one output should be shorted at a time and duration of the short-circuit should not exceed one second. V_{OUT} = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Descriptions	Test Conditions		Typ.	Unit
C_{IN}	Input Capacitance	V_{IN} = 2.0 V	V_{CC} = 5.0 V, T_A = 25°C,	5	pF
C_{OUT}	Output Capacitance	V_{OUT} = 2.0 V	f = 1 MHz	8	pF

Note:

1. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

Parameter Symbol	Parameter Description			Min.	Max.	Unit
t_{PD}	Input or Feedback to Combinatorial Output				10	ns
t_S	Setup Time from Input or Feedback to Clock			7.5		
t_H	Hold Time			0		ns
t_{CO}	Clock to Output				7.5	ns
t_{WL}	Clock Width	LOW		6		ns
t_{WH}		HIGH		6		ns
f_{MAX}	Maximum Frequency (Note 3)	External Feedback	1/(ts+tco)	66.7		MHz
		Internal Feedback (f_{CNT})		71.4		MHz
		No Feedback	1/(t_{WH}+t_{WL})	83.3		MHz
t_{PZX}	$\overline{OE}$ to Output Enable				10	ns
t_{PXZ}	$\overline{OE}$ to Output Disable				10	ns
t_{EA}	Input to Output Enable Using Product Term Control				10	ns
t_{ER}	Input to Output Disable Using Product Term Control				10	ns

Notes:

2. See Switching Test Circuit for test conditions.
3. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.

ABSOLUTE MAXIMUM RATINGS

Storage Temperature	−65°C to +150°C
Ambient Temperature with Power Applied	−55°C to +125°C
Supply Voltage with Respect to Ground	−0.5 V to +7.0 V
DC Input Voltage	−0.5 V to V_{CC} + 0.5 V
DC Output or I/O Pin Voltage	−0.5 V to V_{CC} + 0.5 V
Static Discharge Voltage	2001 V
Latchup Current (T_A = 0°C to 75°C)	100 mA

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

OPERATING RANGES

Commercial (C) Devices

Temperature (T_A) Operating in Free Air	0°C to +75°C
Supply Voltage (V_{CC}) with Respect to Ground	+4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions		Min.	Max.	Unit
V_{OH}	Output HIGH Voltage	I_{OH} = −3.2 mA V_{IN} = V_{IH} or V_{IL} V_{CC} = Min.		2.4		V
V_{OL}	Output LOW Voltage	I_{OL} = 24 mA V_{IN} = V_{IH} or V_{IL} V_{CC} = Min.			0.5	V
V_{IH}	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)		2.0		V
V_{IL}	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)			0.8	V
I_{IH}	Input HIGH Leakage Current	V_{IN} = 5.25 V, V_{CC} = Max. (Note 2)			10	µA
I_{IL}	Input LOW Leakage Current	V_{IN} = 0 V, V_{CC} = Max. (Note 2)			−10	µA
I_{OZH}	Off-State Output Leakage Current HIGH	V_{OUT} = 5.25 V, V_{CC} = Max. V_{IN} = V_{IH} or V_{IL} (Note 2)			10	µA
I_{OZL}	Off-State Output Leakage Current LOW	V_{OUT} = 0 V, V_{CC} = Max. V_{IN} = V_{IH} or V_{IL} (Note 2)			−10	µA
I_{SC}	Output Short-Circuit Current	V_{OUT} = 0.5 V V_{CC} = Max. (Note 3)		−30	−150	mA
I_{CC}	Supply Current (Dynamic)	Outputs Open (I_{OUT} = 0 mA) V_{CC} = Max., f = 25 MHz	H		90	mA
			Q		55	

Notes:

1. These are absolute values with respect to device ground and all overshoots due to system or tester noise are included.
2. I/O pin leakage is the worst case of I_{IL} and I_{OZL} (or I_{IH} and I_{OZH}).
3. Not more than one output should be shorted at a time and duration of the short-circuit should not exceed one second. V_{OUT} = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Descriptions	Test Conditions		Typ.	Unit
C_{IN}	Input Capacitance	V_{IN} = 2.0 V	V_{CC} = 5.0 V, T_A = 25°C,	5	pF
C_{OUT}	Output Capacitance	V_{OUT} = 2.0 V	f = 1 MHz	8	pF

Note:

1. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

Parameter Symbol	Parameter Description			-15 Min.	-15 Max.	-25 Min.	-25 Max.	Unit
t_{PD}	Input or Feedback to Combinatorial Output				15		25	ns
t_S	Setup Time from Input or Feedback to Clock			12		15		
t_H	Hold Time			0		0		ns
t_{CO}	Clock to Output				10		12	ns
t_{WL}	Clock Width	LOW		8		12		ns
t_{WH}		HIGH		8		12		ns
f_{MAX}	Maximum Frequency (Note 3)	External Feedback	1/(t_S+t_{CO})	45.5		37		MHz
		Internal Feedback (f_{CNT})		50		40		MHz
		No Feedback	1/(t_{WH}+t_{WL})	62.5		41.6		MHz
t_{PZX}	$\overline{OE}$ to Output Enable				15		20	ns
t_{PXZ}	$\overline{OE}$ to Output Disable				15		20	ns
t_{EA}	Input to Output Enable Using Product Term Control				15		20	ns
t_{ER}	Input to Output Disable Using Product Term Control				15		20	ns

Notes:

2. See Switching Test Circuit for test conditions.
3. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.

ABSOLUTE MAXIMUM RATINGS

Storage Temperature	−65°C to +150°C
Ambient Temperature with Power Applied	−55°C to +125°C
Supply Voltage with Respect to Ground	−0.5 V to +7.0 V
DC Input Voltage	−0.5 V to V_{CC} + 1.0 V
DC Output or I/O Pin Voltage	−0.5 V to V_{CC} + 1.0 V
Static Discharge Voltage	2001 V
Latchup Current (Tc = −55°C to +125°C)	100 mA

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

OPERATING RANGES

Military (M) Devices (Note 1)

Operating Case Temperature (Tc)	−55°C to +125°C
Supply Voltage (V_{CC}) with Respect to Ground	+4.5 V to +5.5 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

Note:

1. Military products are tested at Tc = +25°C, +125°C and −55°C, per MIL-STD-883.

DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

PRELIMINARY

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
V_{OH}	Output HIGH Voltage	I_{OH} = −2.0 mA V_{IN} = V_{IH} or V_{IL} V_{CC} = Min.	2.4		V
V_{OL}	Output LOW Voltage	I_{OL} = 12 mA V_{IN} = V_{IH} or V_{IL} V_{CC} = Min.		0.5	V
V_{IH}	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		V
V_{IL}	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	V
I_{IH}	Input HIGH Leakage Current	V_{IN} = 5.5 V, V_{CC} = Max. (Note 4)		10	µA
I_{IL}	Input LOW Leakage Current	V_{IN} = 0 V, V_{CC} = Max. (Note 4)		−100	µA
I_{OZH}	Off-State Output Leakage Current HIGH	V_{OUT} = 5.5 V, V_{CC} = Max. V_{IN} = V_{IH} or V_{IL} (Note 4)		10	µA
I_{OZL}	Off-State Output Leakage Current LOW	V_{OUT} = 0 V, V_{CC} = Max. V_{IN} = V_{IH} or V_{IL} (Note 4)		−100	µA
I_{SC}	Output Short-Circuit Current	V_{CC} = 5.0 V, V_{OUT} = 0.5 V (Note 5), T = 25°C	−30	−150	mA
I_{CC}	Supply Current (Dynamic)	Outputs Open (I_{OUT} = 0 mA) V_{CC} = Max., f = 25 MHz		130	mA

Notes:

2. For APL products, Group A, Subgroups 1, 2 and 3 are tested per MIL-STD-833, Method 5005, unless otherwise noted.
3. V_{IL} and V_{IH} are input conditions of output tests and are not themselves directly tested. V_{IL} and V_{IH} are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
4. I/O pin leakage is the worst case of I_{IL} and I_{OZL} (or I_{IH} and I_{OZH}).
5. Not more than one output should be shorted at a time and duration of the short-circuit should not exceed one second. V_{OUT} = 0.5 V has been chosen to avoid test problems caused by tester ground degradation. This parameter is not 100% tested, but is evaluated at initial characterization and at any time the design is modified where I_{SC} may be affected.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Descriptions	Test Conditions		Typ.	Unit
C_{IN}	Input Capacitance	V_{IN} = 2.0 V	V_{CC} = 5.0 V, T_A = 25°C, f = 1 MHz	8	pF
C_{OUT}	Output Capacitance	V_{OUT} = 2.0 V		8	pF

Note:

1. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 2)

PRELIMINARY

Parameter Symbol	Parameter Description			Min.	Max.	Unit
t_{PD}	Input or Feedback to Combinatorial Output				10	ns
t_S	Setup Time from Input or Feedback to Clock			10		ns
t_H	Hold Time			0		ns
t_{CO}	Clock to Output				7	ns
t_{WL}	Clock Width	LOW		8		ns
t_{WH}		HIGH		8		ns
f_{MAX}	Maximum Frequency (Note 3)	External Feedback	$1/(t_S+t_{CO})$	58.5		MHz
		Internal Feedback (f_{CNT})		62.5		MHz
		No Feedback	$1/(t_{WH}+t_{WL})$	62.5		MHz
t_{PZX}	$\overline{OE}$ to Output Enable (Note 3)				10	ns
t_{PXZ}	$\overline{OE}$ to Output Disable (Note 3)				10	ns
t_{EA}	Input to Output Enable Using Product Term Control (Note 3)				10	ns
t_{ER}	Input to Output Disable Using Product Term Control (Note 3)				10	ns

Notes:

2. See Switching Test Circuit for test conditions. For APL Products, Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
3. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

ABSOLUTE MAXIMUM RATINGS

Storage Temperature	−65°C to +150°C
Ambient Temperature with Power Applied	−55°C to +125°C
Supply Voltage with Respect to Ground	−0.5 V to +7.0 V
DC Input Voltage	−0.5 V to V_{CC} + 1.0 V
DC Output or I/O Pin Voltage	−0.5 V to V_{CC} + 1.0 V
Static Discharge Voltage	2001 V
Latchup Current (Tc = −55°C to +125°C)	100 mA

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

OPERATING RANGES

Military (M) Devices (Note 1)

Operating Case Temperature (Tc)	−55°C to +125°C
Supply Voltage (V_{CC}) with Respect to Ground	+4.5 V to +5.5 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

Note:

1. Military products are tested at Tc = +25°C, +125°C and −55°C, per MIL-STD-883.

DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
V_{OH}	Output HIGH Voltage	I_{OH} = −2.0 mA V_{IN} = V_{IH} or V_{IL} V_{CC} = Min.	2.4		V
V_{OL}	Output LOW Voltage	I_{OL} = 12 mA V_{IN} = V_{IH} or V_{IL} V_{CC} = Min.		0.5	V
V_{IH}	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		V
V_{IL}	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	V
I_{IH}	Input HIGH Leakage Current	V_{IN} = 5.5 V, V_{CC} = Max. (Note 4)		10	µA
I_{IL}	Input LOW Leakage Current	V_{IN} = 0 V, V_{CC} = Max. (Note 4)		−10	µA
I_{OZH}	Off-State Output Leakage Current HIGH	V_{OUT} = 5.5 V, V_{CC} = Max. V_{IN} = V_{IH} or V_{IL} (Note 4)		10	µA
I_{OZL}	Off-State Output Leakage Current LOW	V_{OUT} = 0 V, V_{CC} = Max. V_{IN} = V_{IH} or V_{IL} (Note 4)		−100	µA
I_{SC}	Output Short-Circuit Current	V_{CC} = 5.0 V, V_{OUT} = 0.5 V (Note 5), T = 25°C	−30	−150	mA
I_{CC}	Supply Current (Dynamic)	Outputs Open (I_{OUT} = 0 mA) V_{CC} = Max., f = 25 MHz		130	mA

Notes:

2. For APL products, Group A, Subgroups 1, 2 and 3 are tested per MIL-STD-833, Method 5005, unless otherwise noted.
3. V_{IL} and V_{IH} are input conditions of output tests and are not themselves directly tested. V_{IL} and V_{IH} are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
4. I/O pin leakage is the worst case of I_{IL} and I_{OZL} (or I_{IH} and I_{OZH}).
5. Not more than one output should be shorted at a time and duration of the short-circuit should not exceed one second. V_{OUT} = 0.5 V has been chosen to avoid test problems caused by tester ground degradation. This parameter is not 100% tested, but is evaluated at initial characterization and at any time the design is modified where I_{SC} may be affected.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Descriptions	Test Conditions		Typ.	Unit
C_{IN}	Input Capacitance	V_{IN} = 2.0 V	V_{CC} = 5.0 V, T_A = 25°C, f = 1 MHz	8	pF
C_{OUT}	Output Capacitance	V_{OUT} = 2.0 V		8	pF

Note:

1. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 2)

Parameter Symbol	Parameter Description			Min.	Max.	Unit
t_{PD}	Input or Feedback to Combinatorial Output				15	ns
t_S	Setup Time from Input or Feedback to Clock			12		ns
t_H	Hold Time			0		ns
t_{CO}	Clock to Output				12	ns
t_{WL}	Clock Width	LOW		10		ns
t_{WH}		HIGH		10		ns
f_{MAX}	Maximum Frequency (Note 3)	External Feedback	$1/(t_S+t_{CO})$	41.6		MHz
		Internal Feedback (f_{CNT})		45.5		MHz
		No Feedback	$1/(t_{WH}+t_{WL})$	50		MHz
t_{PZX}	$\overline{OE}$ to Output Enable (Note 3)				15	ns
t_{PXZ}	$\overline{OE}$ to Output Disable (Note 3)				15	ns
t_{EA}	Input to Output Enable Using Product Term Control (Note 3)				15	ns
t_{ER}	Input to Output Disable Using Product Term Control (Note 3)				15	ns

Notes:

2. See Switching Test Circuit for test conditions. For APL Products, Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
3. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

ABSOLUTE MAXIMUM RATINGS

Storage Temperature	−65°C to +150°C
Ambient Temperature with Power Applied	−55°C to +125°C
Supply Voltage with Respect to Ground	−0.5 V to +7.0 V
DC Input Voltage	−0.5 V to V_{CC} + 1.0 V
DC Output or I/O Pin Voltage	−0.5 V to V_{CC} + 1.0 V
Static Discharge Voltage	2001 V
Latchup Current (T_C = −55°C to +125°C)	100 mA

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

OPERATING RANGES

Military (M) Devices (Note 1)

Operating Case Temperature (T_C)	−55°C to +125°C
Supply Voltage (V_{CC}) with Respect to Ground	+4.5 V to +5.5 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

Note:

1. Military products are tested at T_C = +25°C, +125°C and −55°C, per MIL-STD-883.

DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
V_{OH}	Output HIGH Voltage	I_{OH} = −2.0 mA V_{IN} = V_{IH} or V_{IL} V_{CC} = Min.	2.4		V
V_{OL}	Output LOW Voltage	I_{OL} = 12 mA V_{IN} = V_{IH} or V_{IL} V_{CC} = Min.		0.5	V
V_{IH}	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		V
V_{IL}	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	V
I_{IH}	Input HIGH Leakage Current	V_{IN} = 5.5 V, V_{CC} = Max. (Note 4)		10	µA
I_{IL}	Input LOW Leakage Current	V_{IN} = 0 V, V_{CC} = Max. (Note 4)		−10	µA
I_{OZH}	Off-State Output Leakage Current HIGH	V_{OUT} = 5.5 V, V_{CC} = Max. V_{IN} = V_{IH} or V_{IL} (Note 4)		10	µA
I_{OZL}	Off-State Output Leakage Current LOW	V_{OUT} = 0 V, V_{CC} = Max. V_{IN} = V_{IH} or V_{IL} (Note 4)		−100	µA
I_{SC}	Output Short-Circuit Current	V_{CC} = 5.0 V, V_{OUT} = 0.5 V (Note 5), T = 25°C	−30	−150	mA
I_{CC}	Supply Current (Dynamic)	Outputs Open (I_{OUT} = 0 mA) V_{CC} = Max., f = 25 MHz		130	mA

Notes:

2. For APL products, Group A, Subgroups 1, 2 and 3 are tested per MIL-STD-833, Method 5005, unless otherwise noted.
3. V_{IL} and V_{IH} are input conditions of output tests and are not themselves directly tested. V_{IL} and V_{IH} are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
4. I/O pin leakage is the worst case of I_{IL} and I_{OZL} (or I_{IH} and I_{OZH}).
5. Not more than one output should be shorted at a time and duration of the short-circuit should not exceed one second. V_{OUT} = 0.5 V has been chosen to avoid test problems caused by tester ground degradation. This parameter is not 100% tested, but is evaluated at initial characterization and at any time the design is modified where I_{SC} may be affected.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Descriptions	Test Conditions		Typ.	Unit
C_{IN}	Input Capacitance	V_{IN} = 2.0 V	V_{CC} = 5.0 V, T_A = 25°C,	8	pF
C_{OUT}	Output Capacitance	V_{OUT} = 2.0 V	f = 1 MHz	8	pF

Note:

1. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

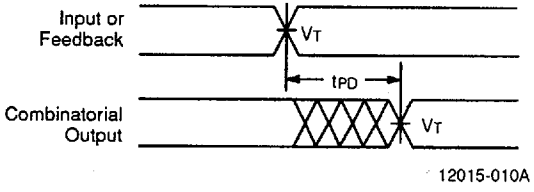
SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 2)

Parameter Symbol	Parameter Description			-20 Min.	-20 Max.	-25 Min.	-25 Max.	Unit
t_{PD}	Input or Feedback to Combinatorial Output				20		25	ns
t_S	Setup Time from Input or Feedback to Clock			15		15		
t_H	Hold Time			0		0		ns
t_{CO}	Clock to Output				15		20	ns
t_{WL}	Clock Width	LOW		12		15		ns
t_{WH}		HIGH		12		15		ns
f_{MAX}	Maximum Frequency (Note 3)	External Feedback	$1/(t_S+t_{CO})$	33.3		28.6		MHz
		Internal Feedback (f_{CNT})		35.7		30.3		MHz
		No Feedback	$1/(t_{WH}+t_{WL})$	41.7		33.3		MHz
t_{PZX}	$\overline{OE}$ to Output Enable (Note 3)				20		20	ns
t_{PXZ}	$\overline{OE}$ to Output Disable (Note 3)				20		20	ns
t_{EA}	Input to Output Enable Using Product Term Control (Note 3)				20		25	ns
t_{ER}	Input to Output Disable Using Product Term Control (Note 3)				20		55	ns

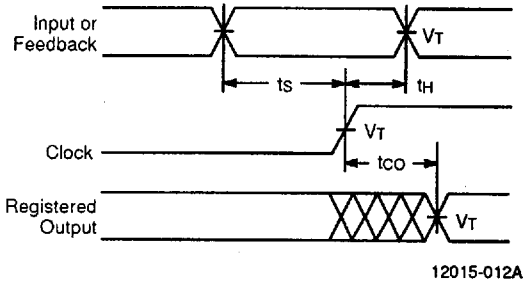
Notes:

2. See Switching Test Circuit for test conditions. For APL Products, Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
3. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

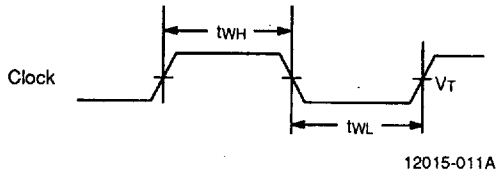
SWITCHING WAVEFORMS



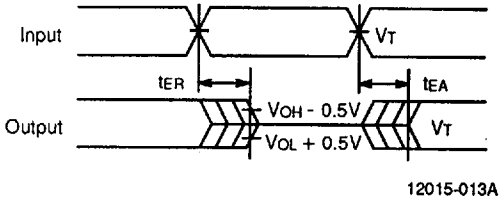
Combinatorial Output



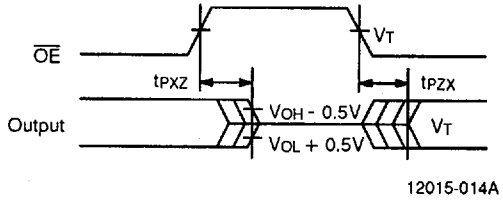
Registered Output



Clock Width



Input to Output Disable/Enable



$\overline{OE}$ to Output Disable/Enable

Notes:

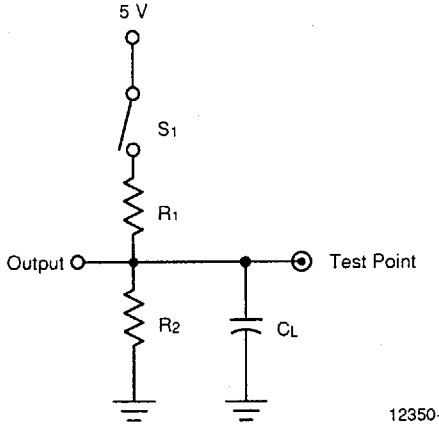
1. V_T = 1.5 V
2. Input pulse amplitude 0 V to 3.0 V.
3. Input rise and fall times 2–5 ns typical.

KEY TO SWITCHING WAVEFORMS

WAVEFORM	INPUTS	OUTPUTS
	Must be Steady	Will be Steady
	May Change from H to L	Will be Changing from H to L
	May Change from L to H	Will be Changing from L to H
	Don't Care, Any Change Permitted	Changing, State Unknown
	Does Not Apply	Center Line is High-Impedance "Off" State

KS000010-PAL

SWITCHING TEST CIRCUIT



12350-019A

Specification	S_1	C_L	Commercial R_1	Commercial R_2	Military R_1	Military R_2	Measured Output Value
t_{PD}, t_{CO}	Closed	50 pF	200 Ω	390 Ω	390 Ω	750 Ω	1.5 V
t_{PZX}, t_{EA}	Z → H: Open Z → L: Closed						1.5 V
t_{PXZ}, t_{ER}	H → Z: Open L → Z: Closed	5 pF					H → Z: V_{OH} – 0.5 V L → Z: V_{OL} + 0.5 V

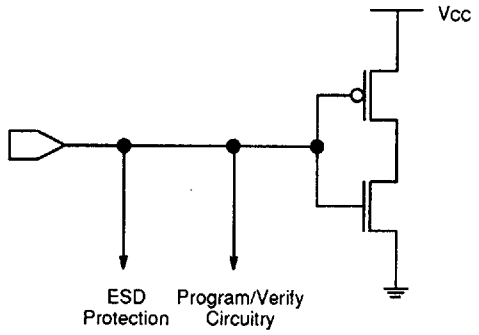
ENDURANCE CHARACTERISTICS

The PALCE16V8 is manufactured using AMD's advanced Electrically Erasable process. This technology uses an EE cell to replace the fuse link used in bipolar parts. As a result, the device can be erased and reprogrammed – a feature which allows 100% testing at the factory.

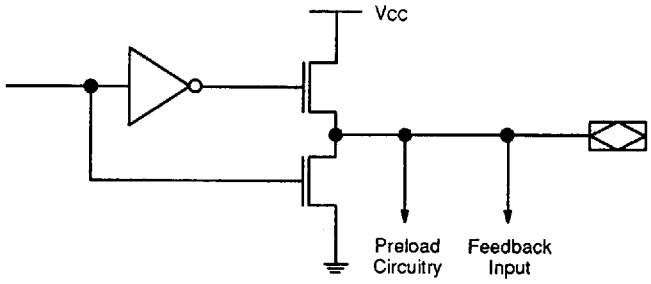
Endurance Characteristics

Symbol	Parameter	Min.	Units	Test Conditions
t_{DR}	Min. Pattern Data Retention Time	10	Years	Max. Storage Temperature
		20	Years	Max. Operating Temperature (Military)
N	Min. Reprogramming Cycles	100	Cycles	Normal Programming Conditions

INPUT/OUTPUT EQUIVALENT SCHEMATICS



Typical Input



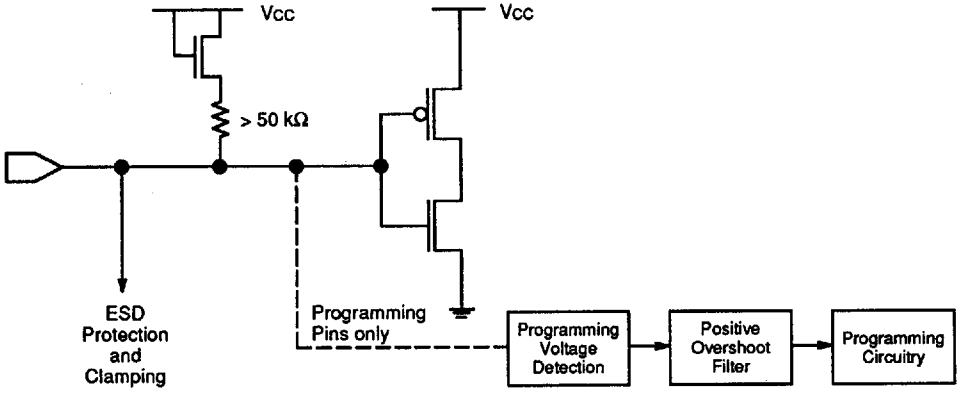
Typical Output

12197-013A

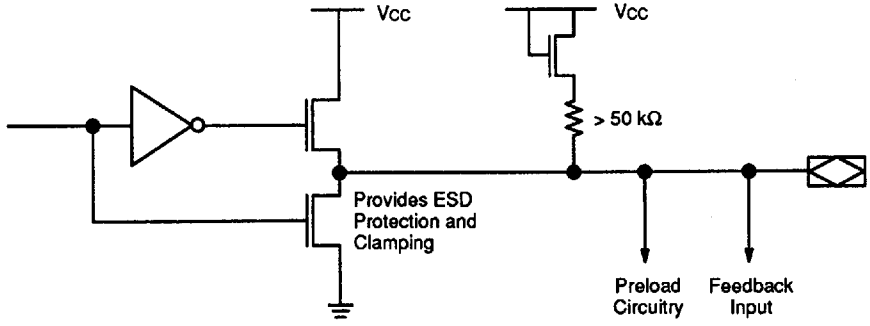
ROBUSTNESS FEATURES FOR /5 VERSIONS

The PALCE16V8H-7/5 has some unique features that make it extremely robust, especially when operating in high-speed design environments. Pull-up resistors on inputs and I/O pins cause unconnected pins to default to a known state. Input clamping circuitry limits negative overshoot, eliminating the possibility of false clocking caused by subsequent ringing. A special noise filter makes the programming circuitry completely insensitive to any positive overshoot that has a pulse width of less than about 100 ns.

INPUT/OUTPUT EQUIVALENT SCHEMATICS FOR /5 VERSION



Typical Input



Typical Output

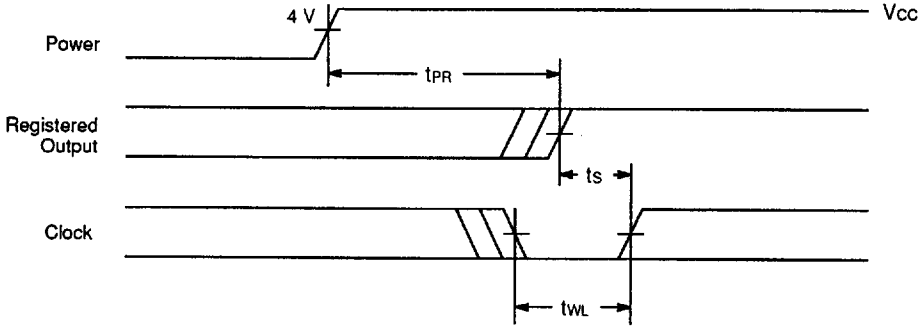
16407A-001B

POWER-UP RESET

The PALCE16V8 has been designed with the capability to reset during system power-up. Following power-up, all flip-flops will be reset to LOW. The output state will be HIGH independent of the logic polarity. This feature provides extra flexibility to the designer and is especially valuable in simplifying state machine initialization. A timing diagram and parameter table are shown below. Due to the synchronous operation of the power-up reset and the wide range of ways Vcc can rise to its steady state, two conditions are required to insure a valid power-up reset. These conditions are:

1. The Vcc rise must be monotonic.
2. Following reset, the clock input must not be driven from LOW to HIGH until all applicable input and feedback setup times are met.

Parameter Symbol	Parameter Descriptions	Min.	Max.	Unit
t_{PR}	Power-Up Reset Time		1000	ns
ts	Input or Feedback Setup Time	See Switching Characteristics		
t_{WL}	Clock Width LOW			



12350-024A

Power-Up Reset Waveform